

Vishay Semiconductors

Small Signal Fast Switching Diode



FEATURES

- Silicon epitaxial planar diode
- Electrical data identical with the device 1N4154
- QuadroMELF package
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912





APPLICATIONS

· Extreme fast switches

ADDITIONAL RESOURCES



MECHANICAL DATA

Case: QuadroMELF (SOD-80)

Weight: approx. 34 mg
Cathode band color: black
Packaging codes / options:

GS18/10K per 13" reel (8 mm tape), 10K/box GS08/2.5K per 7" reel (8 mm tape), 12.5K/box

PARTS TABLE					
PART	ORDERING CODE	TYPE MARKING	CIRCUIT CONFIGURATION	REMARKS	
LS4154	LS4154GS18 or LS4154GS08	-	Single	Tape and reel	

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
Repetitive peak reverse voltage		V_{RRM}	35	V		
Reverse voltage		V _R	25	V		
Peak forward surge current	t _p = 1 μs	I _{FSM}	2	Α		
Repetitive peak forward current		I _{FRM}	500	mA		
Forward continuous current		I _F	300	mA		
Average forward current	V _R = 0	I _{F(AV)}	150	mA		
Power dissipation		P _{tot}	500	mW		

THERMAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Thermal resistance junction to ambient air	On PC board 50 mm x 50 mm x 1.6 mm	R _{thJA}	500	K/W	
Junction temperature		Tj	175	°C	
Storage temperature range		T _{stg}	-65 to +175	°C	



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ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I _F = 30 mA	V _F			1	V
Reverse voltage	V _R = 25 V	I _R			100	nA
neverse voltage	$V_R = 25 \text{ V}, T_j = 150 \text{ °C}$	I _R			100	μA
Breakdown voltage	$I_R = 5 \mu A, t_p/T = 0.01,$ $t_p = 0.3 \text{ ms}$	V _(BR)	35			V
Diode capacitance	$V_R = 0$, $f = 1$ MHz, $V_{HF} = 50$ mV	C _D			4	pF
	$I_F = I_R = 10 \text{ mA}, i_R = 1 \text{ mA}$	t _{rr}			4	ns
Reverse recovery time	I_F = 10 mA, V_R = 6 V, i_R = 0.1 x I_R , R_L = 100 Ω	t _{rr}			2	ns

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

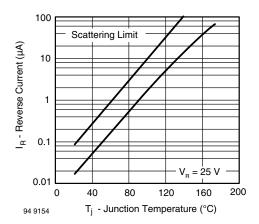


Fig. 1 - Reverse Current vs. Junction Temperature

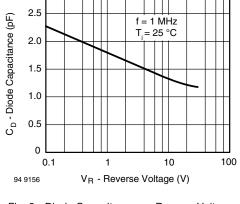


Fig. 3 - Diode Capacitance vs. Reverse Voltage

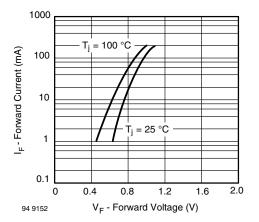
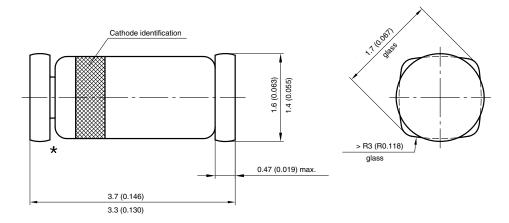


Fig. 2 - Forward Current vs. Forward Voltage

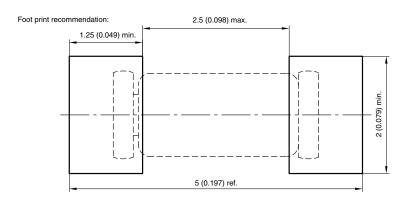


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PACKAGE DIMENSIONS in millimeters (inches): QuadroMELF (SOD-80)



★ The gap between plug and glass can be either on cathode or anode side



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